



2SB1144/2SD1684

100V/1.5A Switching Applications

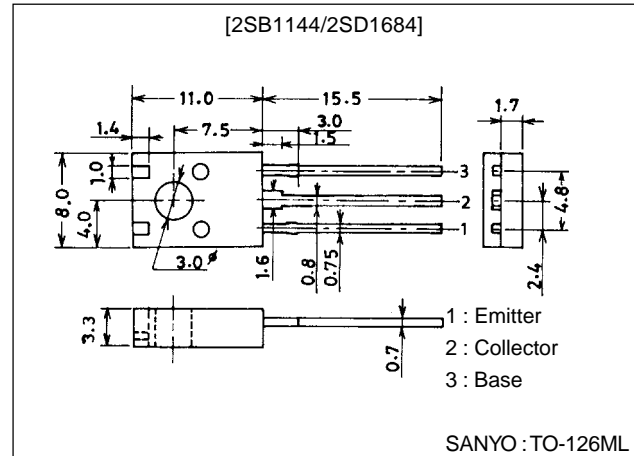
Features

- Adoption of FBET and MBIT processes.
- High breakdown voltage.
- Low saturation voltage.
- Plastic-covered heat sink facilitating high-density mounting.

Package Dimensions

unit:mm

2042B



() : 2SB1144

Specifications

Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CB0}		(-)120	V
Collector-to-Emitter Voltage	V_{CE0}		(-)100	V
Emitter-to-Base Voltage	V_{EB0}		(-)6	V
Collector Current	I_C		(-)1.5	A
Collector Current (Pulse)	I_{CP}		(-)2.0	A
Collector Dissipation	P_C		1.5	W
		$T_c=25^\circ\text{C}$	10	W
Junction Temperature	T_j		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

Electrical Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB}=(-)100\text{V}, I_E=0$			(-)100	nA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=(-)4\text{V}, I_C=0$			(-)100	nA
DC Current Gain	h_{FE1}	$V_{CE}=(-)5\text{V}, I_C=(-)100\text{mA}$	100*		400*	
	h_{FE2}	$V_{CE}=(-)5\text{V}, I_C=(-)1\text{A}$	30			
Gain-Bandwidth Product	f_T	$V_{CE}=(-)10\text{V}, I_C=(-)50\text{mA}$		(100)		MHz
				120		MHz
Output Capacitance	C_{ob}	$V_{CB}=(-)10\text{V}, f=1\text{MHz}$		11(18)		pF

* : The 2SB1144/2SD1684 are classified by 100mA h_{FE} as follows :

100	Q	200	140	S	280	200	T	400
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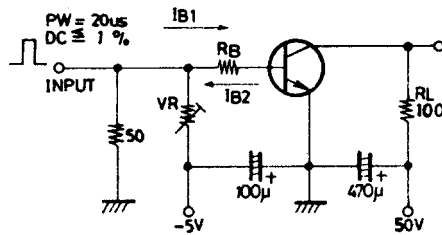
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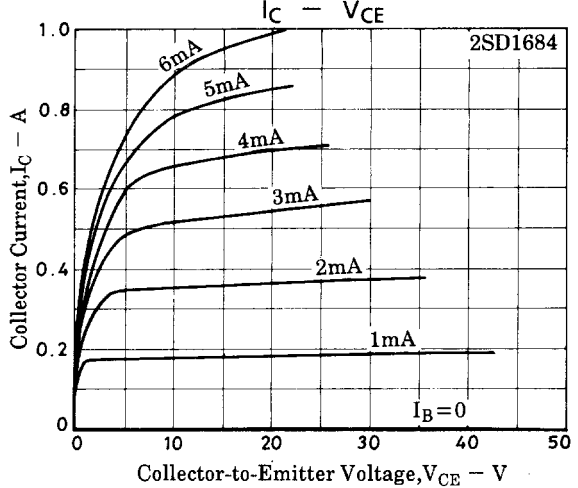
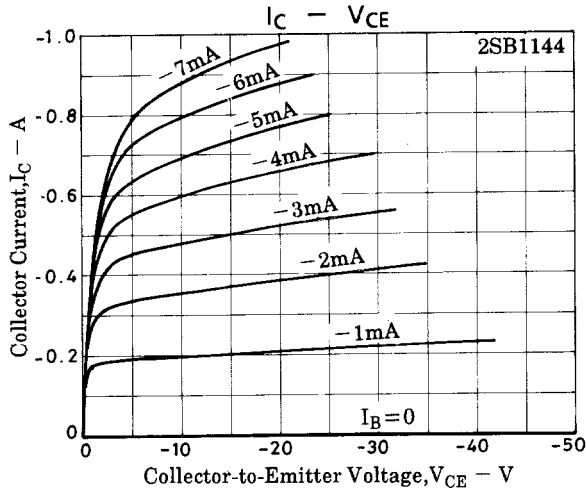
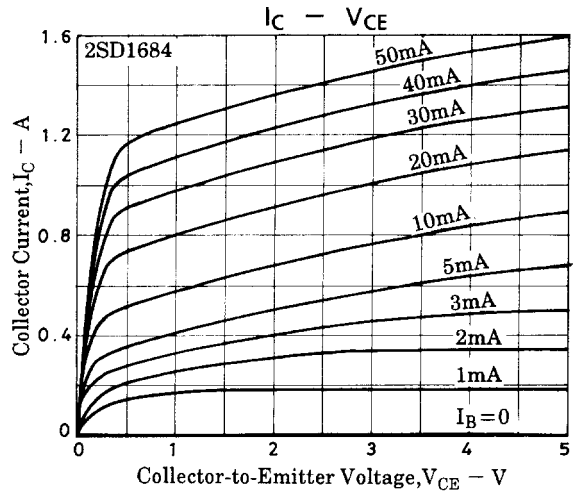
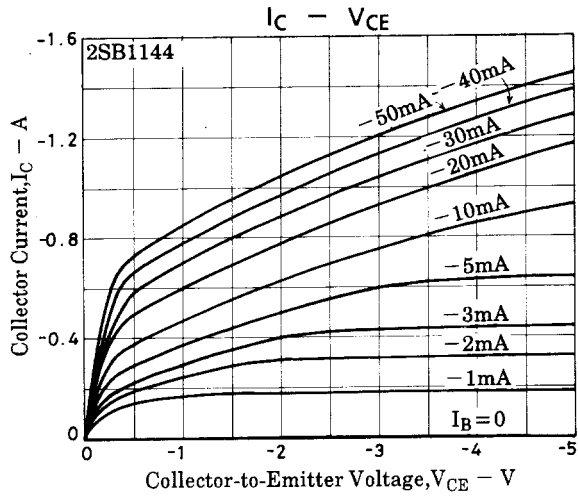
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=(-)500mA, I_B=(-)50mA$		(-180)	(-500)	mV
				100	300	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=(-)500mA, I_B=(-)50mA$		(-0.85)	(-1.2)	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=(-)10\mu A, I_E=0$	(-120)			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=(-)1mA, R_{BE}=\infty$	(-100)			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=(-)10\mu A, I_C=0$	(-6)			V
Turn-ON Time	t_{on}	See specified Test Circuit		(80)80		ns
Storage Time	t_{stg}	See specified Test Circuit		1000		ns
				(750)		ns
Fall Time	t_f	See specified Test Circuit		(40)50		ns

Switching Time Test Circuit

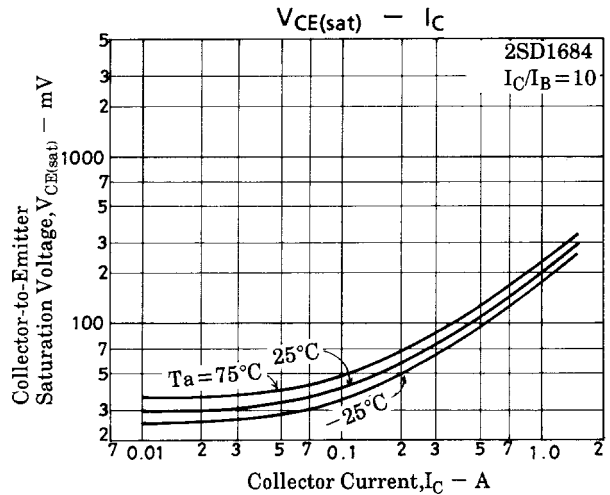
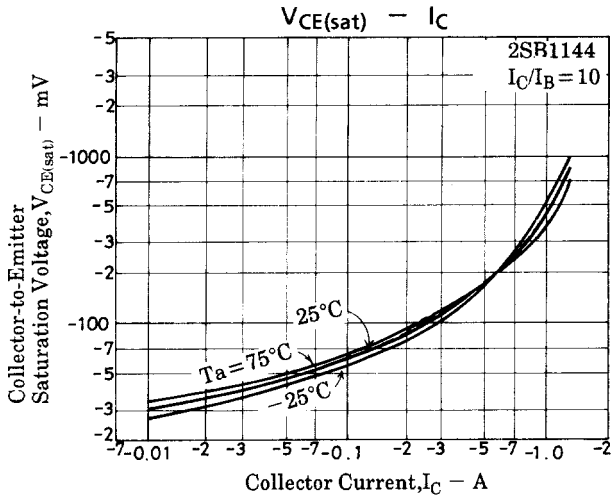
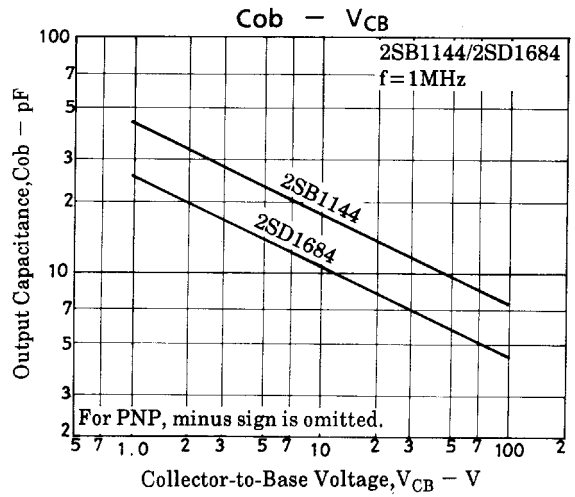
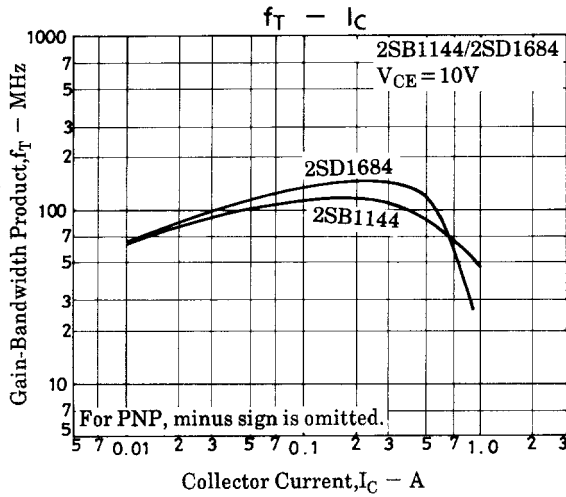
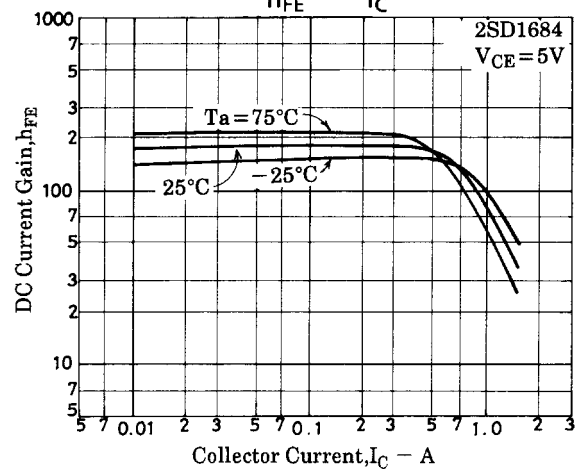
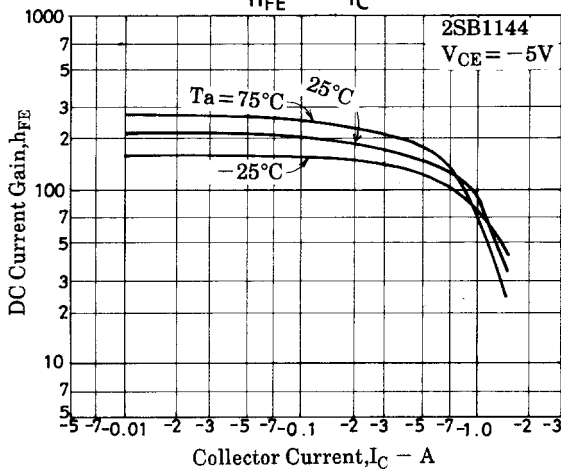
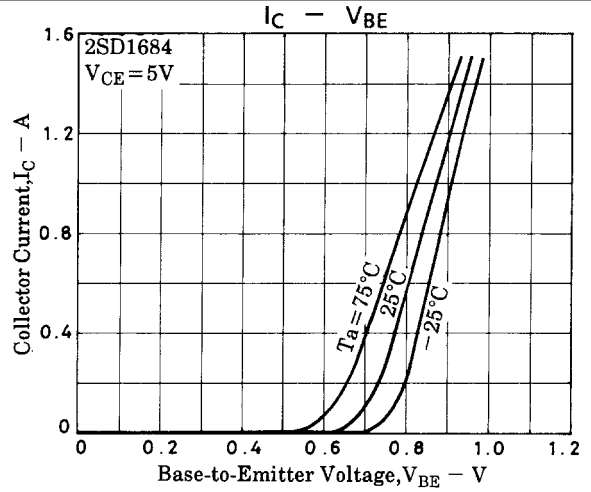
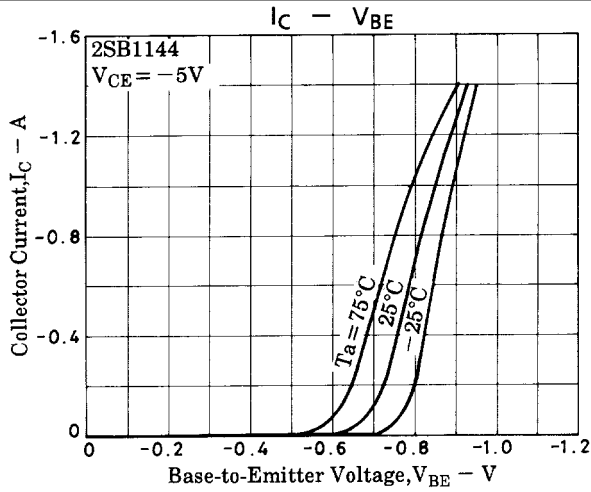


$$I_C = 10I_{B1} = -10I_{B2} = 500mA$$

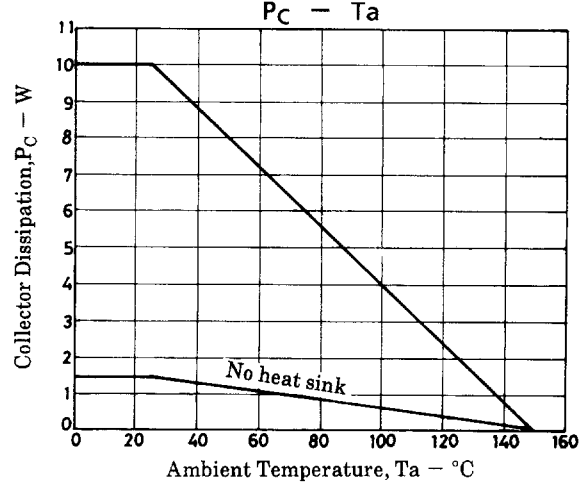
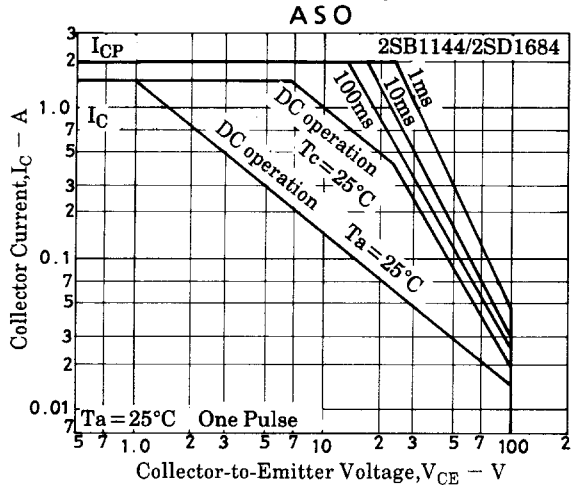
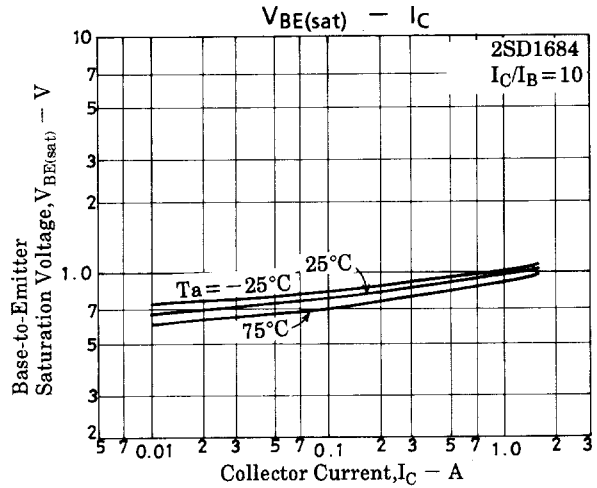
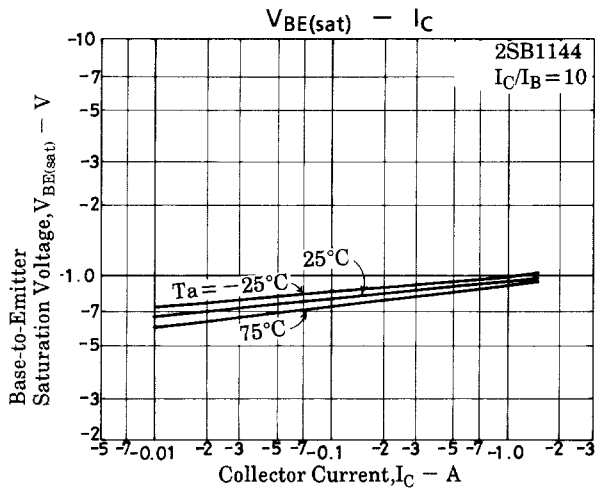
Unit (resistance : Ω , capacitance : F)



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